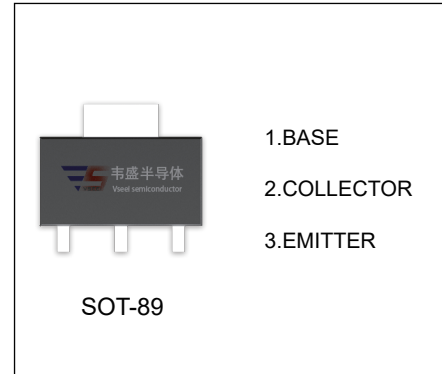


KTC4372 TRANSISTOR (NPN)

FEATURES

- Small Flat Package
- High Voltage Switching Application
- High Voltage
- High Transition Frequency



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	200	V
V _{CEO}	Collector-Emitter Voltage	150	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	50	mA
P _C	Collector Power Dissipation	500	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	250	°C/W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA, I _E =0	200			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =1mA, I _B =0	150			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =0.1mA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =200V, I _E =0			100	nA
Emitter cut-off current	I _{EBO}	V _{EB} =5V, I _C =0			100	nA
DC current gain	h _{FE}	V _{CE} =5V, I _C =10mA	70		240	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =10mA, I _B =1mA			0.5	V
Base-emitter voltage	V _{BE}	V _{CE} =5V, I _C =30mA			1	V
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz			5	pF
Transition frequency	f _T	V _{CE} =30V, I _C = 10mA		120		MHz

CLASSIFICATION OF h_{FE}

RANK	O	Y
RANGE	70 - 140	120 - 240
MARKING	AO	AY